

BOUBAKER POLYNOMIALS EXPANSION SCHEME (BPES)–RELATED
OPTICAL PROPERTIES OF β -SnS₂ SPRAYED LAYERS

C. KHÉLIA, K. BOUBAKER¹ and M. AMLOUK

UPDS, Faculté des Sciences de Tunis, Campus Universitaire, 2092 Tunis

Received 21 September 2008; Revised manuscript received 31 July 2009

Accepted 2 September 2009 Online 18 September 2009

β -SnS₂ layers have been prepared on glass substrates by spray pyrolysis technique at temperature $T_s \approx 270^\circ\text{C}$. The transmission-reflectance spectra, subjected to an original BPES-related protocol, led to accurate calculations of the effective absorptivity. The knowledge of lastly obtained values of the thermal diffusivity allowed the determination of the opto-thermal expansivity ψ_{AB} as a guide to evaluating the conjoint optical and thermal performances of the as-grown layers.

PACS numbers: 78.20.Ci, 81.15.Rs, 85.60.-q

UDC 538.958

Keywords: effective absorptivity, spray pyrolysis, opto-thermal expansivity

1. Introduction

β -SnS₂ tin disulfide is a layered two-dimensional semiconductor with an indirect band gap at 2.2 eV. Its layered structure, as well as its gap, makes it useful for several applications. Tin disulfide and derived ternary alloys magnetic and electrical properties [1–4] make their compounds suitable as absorbers or window layers in photovoltaic (PV) solar cells.

In 2002, Soliman et al. [5] studied the structural and electrical properties of similar chalcogenides thin films and yielded interesting spectral response of thermal measurements. These results were confirmed by the works of B. A. Mansour et al. [6] who investigated quaternary thin layers grown at various temperatures. They carried out an interesting study of the optical behavior changes observed in the structural phases with the growth temperature during the film formation. In 2004, Salem et al. [7] prepared annealed ternary thin films on appropriate substrates and studied their interesting optical properties. More recently, El-Nahass et al. [8] reported UV spectra of metal-free phtalocyanine SnS₂-like thin films.

In most of these studies [3–8], the fabrication processes (deposition in acidic

¹Corresponding author: boubaker_karem@yahoo.com

bath, electro-deposition, successive ionic layer adsorption and reaction (SILAR) etc.) were criticized to be expensive and slow. In this paper, as grown β -SnS₂ layers prepared with low-cost and rapid techniques were subjected to structural and optical investigations as guides to the determination of intrinsic characteristics.

2. Growth of layers and characterization techniques

Tin disulfide layers have been deposited on 0.5 mm thick glass substrates. The precursor solution was a mixture of SnCl₄ and SC(NH₂)₂. Precursor solution and gas flow rates were respectively 1.5 l/min and 4 l/min. Cross micrographs enabled to estimate the as-grown layers thickness. Under the mentioned conditions, the thickness of the deposited layers lie between 1.3 and 1.8 μ m.

Layers transmittance and the reflectance measurements were carried out by a 400–2000 nm wavelength-range spectrophotometer (Shimadzu UV 3100F). XRD measurements have been carried out with a double-beam Philips (PW 3710) apparatus. Common techniques: atomic force microscopy (AFM) and scanning electron microscopy (SEM) were applied for the analyzes of layer's surface.

For calculations purposes, the thermal diffusivity of the layers has been deduced from precedent studies [9–10].

3. Results and discussion

3.1. Structure investigations

XRD patterns (Fig. 1) show that the layers crystallize with a strong (001) X-ray diffraction peak which indicates a strongly c-axis oriented crystallites perpendicular to the lower plane. The second minor peak (101) is also characteristic to β -structured sulfides. The surface morphology, revealed by Figs. 2a and 2b), shows a

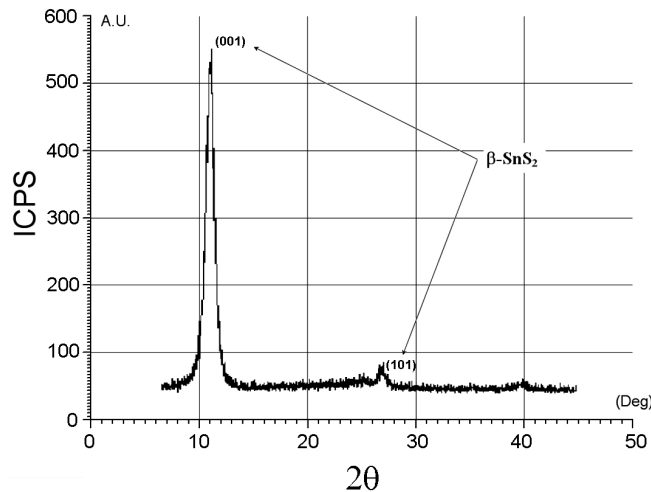


Fig. 1. X-ray diffraction spectrum of β -SnS₂ layers.

dense columnar structure and a periodically homogenous surface. This result is in good agreement with XRD observations.

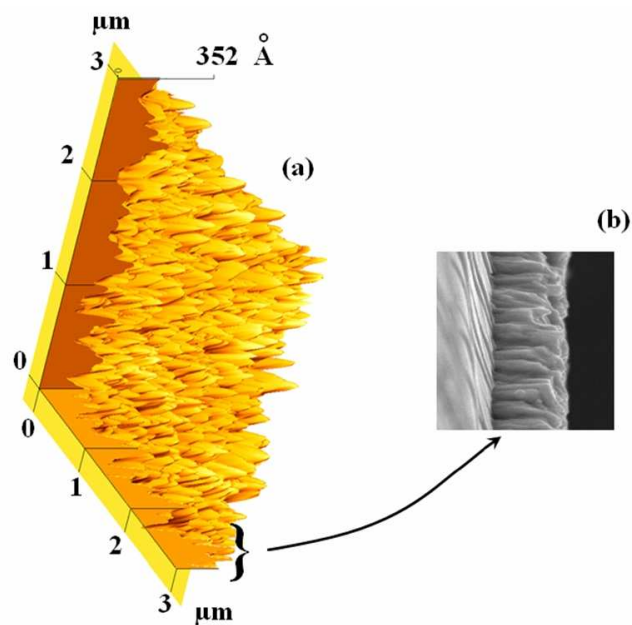


Fig. 2. (a) AFM and (b) SEM micrographs of β -SnS₂ layers.

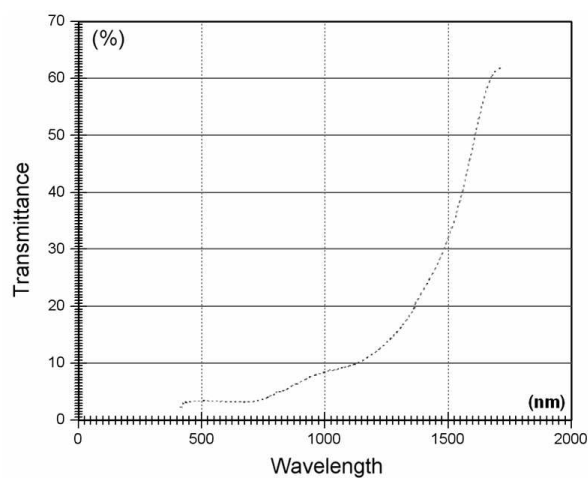


Fig. 3. Transmittance spectrum of β -SnS₂ layers.

3.2. Optical properties

Figures 3 and 4 present, respectively, the transmission and reflectance spectra of the as grown β -SnS₂ layers. It is noted that the transmission coefficient increases

with the wavelength. The β -SnS₂ layer obtained at the temperature $T_s \approx 270^\circ\text{C}$ is transparent both in the visible domain ($T = 40\%$) and the near-IR ($T = 70\%$). The reflectance seems to oscillate in a narrow range (20–25%) in the visible domain and the near-IR.

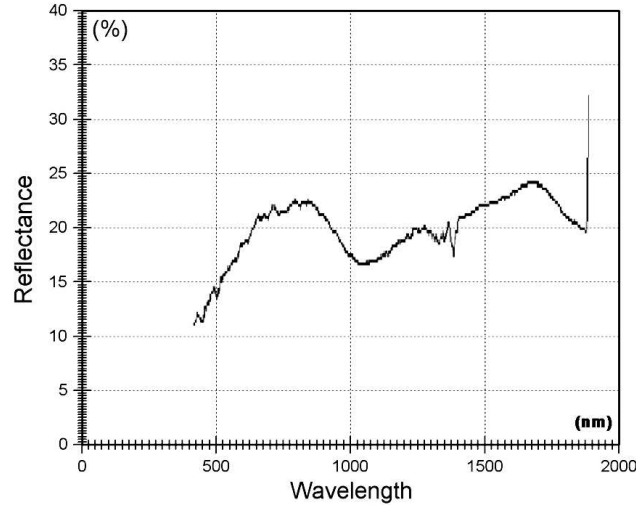


Fig. 4. Reflectance spectrum of β -SnS₂ layers.

The effective absorptivity $\hat{\alpha}$ has been defined [11] as the mean normalized absorbance (Fig. 5) weighted by $I(\tilde{\lambda})_{\text{AMI}5}$, the solar standard irradiance, where $\tilde{\lambda}$ the normalised wavelength

$$\tilde{\lambda} = \frac{\lambda - \lambda_{\min}}{\lambda_{\max} - \lambda_{\min}}, \quad \lambda_{\min} = 400.00 \text{ nm}, \quad \lambda_{\max} = 2000.00 \text{ nm}, \quad (1)$$

and

$$\hat{\alpha} = \frac{\int_0^1 I(\tilde{\lambda})_{\text{AMI}5} \alpha(\tilde{\lambda}) d\tilde{\lambda}}{\int_0^1 I(\tilde{\lambda})_{\text{AMI}5} d\tilde{\lambda}}, \quad (2)$$

where $I(\tilde{\lambda})_{\text{AMI}5}$ is the Reference Solar Spectral Irradiance, fitted using the Boubaker polynomials expansion scheme (BPES) [12–17]

$$I(\tilde{\lambda})_{\text{AMI}5} = \frac{1}{2N_0} \sum_1^{N_0} \theta_n B_{4n}(\tilde{\lambda} \beta_n),$$

where β_n are the Boubaker polynomials [14–17], B_{4n} the minimal positive roots, θ_n the given coefficients, N_0 is a given integer, and $\alpha(\tilde{\lambda})$ is the normalized absorbance spectrum. In precedent studies [9–11], the normalized absorbance spectrum was

deduced from the BPES, applied to the set of m experimental measured values of the transmittance-reflectance vector $\left(T_i(\tilde{\lambda}_i); R_i(\tilde{\lambda}_i)\right)_{i=1, \dots, m}$ versus the normalized wavelength $\lambda_i|_{i=1, \dots, m}$ defined in Eq. (1)

$$R(\tilde{\lambda}) = \frac{1}{2N_0} \sum_{n=1}^{N_0} \xi_n B_{4n}(\tilde{\lambda} \beta_n) \quad (3)$$

$$T(\tilde{\lambda}) = \frac{1}{2N_0} \sum_{n=1}^{N_0} \xi'_n B_{4n}(\tilde{\lambda} \beta_n) \quad (4)$$

where β_n are the minimal positive roots of $4n$ -Boubaker polynomials B_{4n} [13–16], N_0 is a prefixed integer and ξ and ξ' are coefficients which minimize the square sums

$$\bar{\omega} = \sum_{i=1}^n \left[\left(R_i(\lambda_i) - \frac{1}{2N_0} \sum_{q=1}^{N_0} \xi_q B_{4q}(\lambda_i \beta_q) \right)^2 + \left(T_i(\lambda_i) - \lim_{N_0 \rightarrow \infty} \frac{1}{2N_0} \sum_{q=1}^{N_0} \xi'_q B_{4q}(\lambda_i \beta_q) \right)^2 \right] \quad (5)$$

Finally, the normalized absorbance spectrum is calculated using the relation

$$\alpha(\tilde{\lambda}) = \frac{1}{d} \sqrt[3]{ \left| \ln \left(\frac{0.08}{1-T(\tilde{\lambda})} \right) \ln \left(\frac{1}{(1-T(\tilde{\lambda}))} \right) \ln \left(\frac{0.64}{1-T(\tilde{\lambda})} \right) \right| } \quad \text{for } \lambda \in [400; 1000] \text{ nm}, \quad (6)$$

$$\alpha(\tilde{\lambda}) = \frac{1}{d} \sqrt[3]{ \left| \ln \left(\frac{0.3}{1-T(\tilde{\lambda})} \right) \ln \left(\frac{1}{(1-T(\tilde{\lambda}))} \right) \ln \left(\frac{0.09}{1-T(\tilde{\lambda})} \right) \right| } \quad \text{for } \lambda \in [1000; 2000] \text{ nm},$$

where d is the layer thickness.

Equations (6) can be simplified as

$$\alpha(\tilde{\lambda}) = \frac{2.311}{d} T(\tilde{\lambda}) = \frac{2.311}{d} \left(1 - \frac{1}{2N_0} \sum_{n=1}^{N_0} (\xi_n + \xi'_n) B_{4n}(\tilde{\lambda} \beta_n) \right) \quad \text{for } \tilde{\lambda} \in [0.0; 0.25] \text{ a.u.}, \quad (7)$$

$$\alpha(\tilde{\lambda}) = \frac{2.047}{d} T(\tilde{\lambda}) = \frac{2.047}{d} \left(1 - \frac{1}{2N_0} \sum_{n=1}^{N_0} (\xi_n + \xi'_n) B_{4n}(\tilde{\lambda} \beta_n) \right) \quad \text{for } \tilde{\lambda} \in [0.25; 1.0] \text{ a.u.}$$

The profile $\alpha(\tilde{\lambda})$ of the room-temperature grown layer is presented in (Fig. 5). The effective absorptivity $\hat{\alpha}$ is calculated using Eqs. (2) and (7).

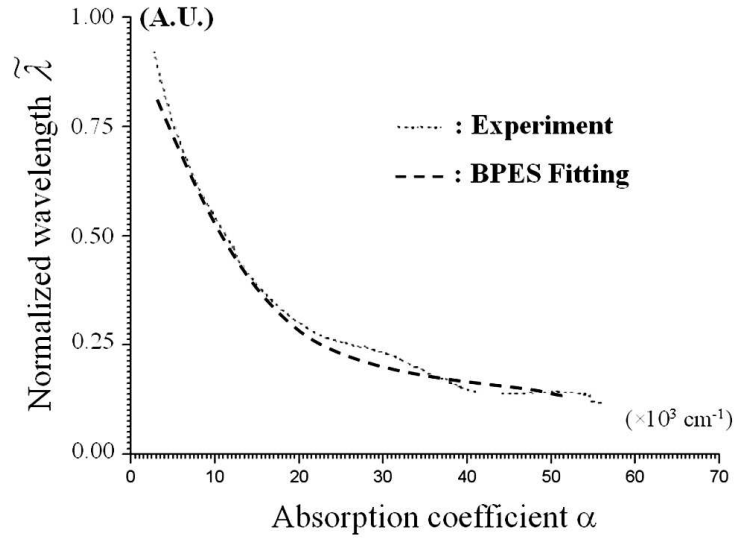


Fig. 5. Absorption coefficient α versus wavelength λ of β -SnS₂.

3.3. Determination of Amlouk-Boubaker opto-thermal expansivity ψ_{AB}

The Amlouk-Boubaker opto-thermal expansivity ψ_{AB} is defined [11] by

$$\psi_{AB} = \frac{D}{\hat{\alpha}} \quad (8)$$

where D is the thermal diffusivity of layer's material and $\hat{\alpha}$ is defined in Eq. (2). The value of this parameter, which is expressed in m³/s, is assimilated to a 3D expansion velocity of the transmitted heat inside the material.

The calculated values of the mean normalized absorbance $\hat{\alpha}$ and the Amlouk-Boubaker opto-thermal expansivity ψ_{AB} , are shown in Table 1.

TABLE 1. Values of the Amlouk-Boubaker opto-thermal expansivity ψ_{AB} .

Parameter	Value	Unit
D	14.5×10^{-6}	m ² s ⁻¹
$\hat{\alpha}$	25.5×10^3	cm ⁻¹
ψ_{AB}	5.68×10^{-12}	m ³ s ⁻¹

The obtained value, $\psi_{AB} = 5.68 \times 10^{-12}$ m³s⁻¹, of the Amlouk-Boubaker opto-thermal expansivity allows comparison with the performance of already investigated binary sulphide-like compounds [11, 18, 19].

4. Conclusion

In this paper, spray pyrolysis deposited β -SnS₂ layers have been investigated. Conjoint XRD, AFM and SEM observations indicate a columnar structure and a periodically homogenous surface. Optical measurements based on the reflectance and transmittance allowed evaluating some relevant optothermal parameters like the mean normalized absorbance $\hat{\alpha}$ and the Amlouk-Boubaker opto-thermal expansivity ψ_{AB} . The relatively low value of the latter parameter is a very promising result since it implies that this material heat retaining capability is lower than of similar compounds [18, 20–23].

Our future investigations are oriented toward deepening Boubaker polynomials expansion scheme (BPES) applications [24–33] as well as obtaining detailed thermal response of the layered β -SnS₂ structures when subjected to modulated heat-light excitations.

Acknowledgements

The authors would like to acknowledge help and assistance from Nargiz Rozibaeva from Uzbek University.

References

- [1] S. Mahmoud and O. Hamid, *Fizika A* **10** (2001) 21.
- [2] I. K. El Zawawi, A. A. ElMoez, F. S. Terra and M. Mounir, *Fizika A* **3** (2001) 97.
- [3] R. D. Engelken, H. E. Mc Coud, C. Lee, M. Slayton and H. Ghoreishi, *J. Electrochem. Soc.* **134** (1987) 2696.
- [4] R. Schlaf, N. R. Armstrong, B. A. Parkinson, C. Pettenkofer and W. Jaegermann, *Surface Science*, **385** (1997) 1.
- [5] L. Soliman, A. M. Abo-El-Soad, H. A. Zayed and S. A. El-Ghfar, *Fizika A* **11** (2002) 139.
- [6] B. A. Mansour, S. A. Abd-El-Hady, A. Abdel-All, I. K. El-Zawawi and H. Shaban, *Fizika A* **12** (2003) 75.
- [7] A. M. Salem and S. H. Moustapha, *Fizika A* **13** (2004) 137.
- [8] M. M. El-Nahass, A. M. Farid, A. A. Attia and H. A. M. Ali, *Fizika A* **15** (2006) 147.
- [9] C. Khlia, F. Maiez, M. Mnari, T. Ben Nasrallah, M. Amlouk and S. Belgacem, *Eur. Phys. J. Ap.* **9** (2000) 187.
- [10] C. Khlia, K. Boubaker, T. Ben Nasrallah, M. Amlouk, S. Belgacem, F. Saadallah and N. Yacoubi, *J. of Crys. Growth* **311** (2009) 1032.
- [11] K. B. Ben Mahmoud and M. Amlouk, *Mat. Lett.*, **63** (2009) 991.
- [12] H. Labiadh and K. M. Boubaker, *Int. J. of App. Math.* **21** (2008) 171.
- [13] K. Boubaker, *Trends in App. Science Res.* **2** (2007) 540.
- [14] H. Labiadh and K. Boubaker, *J. Diff. Eq. and C. P.* **2** (2007) 117.
- [15] J. Ghanouchi, H. Labiadh and K. Boubaker, *Int. J. of Heat and Tech.* **26** (2008) 49.

- [16] A. Chaouachi, K. Boubaker, M. Amlouk and H. Bouzouita, *Eur. Phys. J. Appl. Phys.* **37** (2007) 105.
- [17] S. Slama, J. Bessrou, K. Boubaker and M. Bouhafs, *Investigation of A3 point maximal front spatial evolution during resistance spot welding using 4q-Boubaker polynomial sequence*, Proc. COTUME 2008 (2008) pp. 79-80,
- [18] Ž. Bihar, A. Bilušić, A. Smontara and J. Dolinšek, *Fizika A* **15** (2006) 51.
- [19] S. Mahmoud and F. Sharaf, *Fizika A* **5** (1996) 205.
- [20] A. Bilušić, Ž. Budrović and A. Smontara, *Fizika A* **10** (2001) 121.
- [21] D. D. Miller and A. Heller, *Nature* **262** (1976) 280.
- [22] L. M. Peter, *J. Electroanal. Chem.* **98** (1979) 49.
- [23] P. K. Mahapatra and C. B. Roy, *Solar Cells* **70** (1983) 225.
- [24] S. Fridjine, K. Boubaker and M. Amlouk, *Canad. J. Phys.* **87** (2009) 653.
- [25] S. Fridjine, K. B. Mahmoud, M. Amlouk and M. Bouhafs, *J. Alloys Comp.* **479** (2009) 457.
- [26] S. Tabatabaei, T. Zhao, O. Awojoyogbe and F. Moses, *Heat Mass Transf.* **45** (2009) 1247.
- [27] A. Belhadj, O. Onyango and N. Rozibaeva, *J. Thermophys. Heat Transf.* **23** (2009) 639.
- [28] T. G. Zhao, Y. X. Wang and K. B. Ben Mahmoud, *Int. J. Math. Comp.* **1** (2008) 13.
- [29] S. Lazzez, K.B. Ben Mahmoud, S. Abroug, F. Saadallah and M. Amlouk, *Current App. Phys.* **9** (2009) 1129.
- [30] S. Fridjine, K. Boubaker and M. Amlouk, *Funct. Mater. Lett.* **2** (2009) 41.
- [31] N. Guezmir, T. Ben Nasrallah, K. Boubaker, M. Amlouk and S. Belgacem, *J. Alloys and Comp.* **481** (2009) 543.
- [32] A. Amlouk, K. Boubaker and M. Amlouk, *J. Alloys and Comp.* **482** (2009) 164.
- [33] O. B. Awojoyogbe, O. P. Faromika, F. O. Moses, M. Dada, K. Boubaker and I. A. Fuwape, *Current App. Phys.* **10** (2009) 289.

BOUBAKEROVA SHEMA RAZVOJA PO POLINOMIMA (BPES) I OPTIČKA SVOJSTVA PRSKANIH SLOJEVA β -SnS₂

Na staklenoj podlozi priredili smo slojeve β -SnS₂ metodom vrućeg prskanja na temperaturi 270°C. Spektri prolazne i odrazne svjetlosti, izvedeni primjenom nove sheme razvoja po Boubakerovim polinomima, omogućili su točno određivanje efektivne apsorptivnosti. Konačno dobiveni podaci za termalnu difuzivnost omogućili su određivanje opto-termičkog širenja ψ_{AB} kao vodilju za određivanje povezanih optičkih i termičkih svojstava svježe pripremljenih slojeva.